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## Description

Vectron's VM-800 Clock Oscillator is the next generation silicon MEMS based stabilized square wave generator with a CMOS output, operating off a 1.8, 2.5 or 3.3V supply.

The VM-800 uses an internal compensation scheme to improve temperature stability which produces temperature performance equivalent to quartz based products.

## Features

- Short Lead Time
- Compact QFN Package
- Low Power
- +1.8V, +2.5V, or +3.3V Operation
- CMOS Output
- Output Frequencies to 150 MHz
- Enable/Disable for Board Test and Debug
- -20/70°C or -40/85°C Operating Temperature
- Industry Standard 5x3.2 SMD Footprint
- Product is Compliant to RoHS Directive and Fully Compatible with Lead Free Assembly

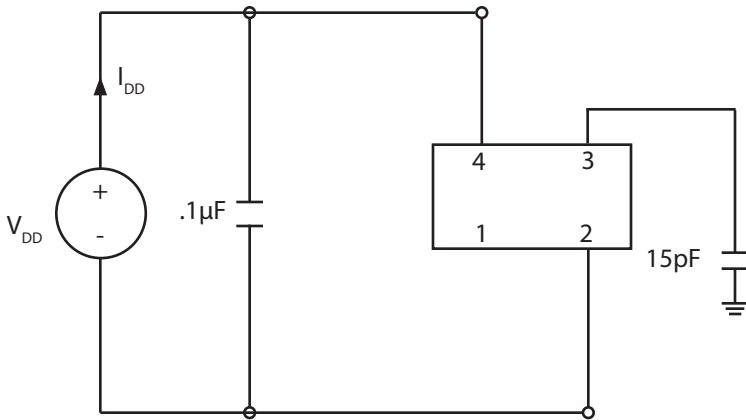
## Applications

- Portable Media Players
- Consumer Electronic Applications
- Printers
- Camera's
- Low Profile Applications
- Computers & Peripherals

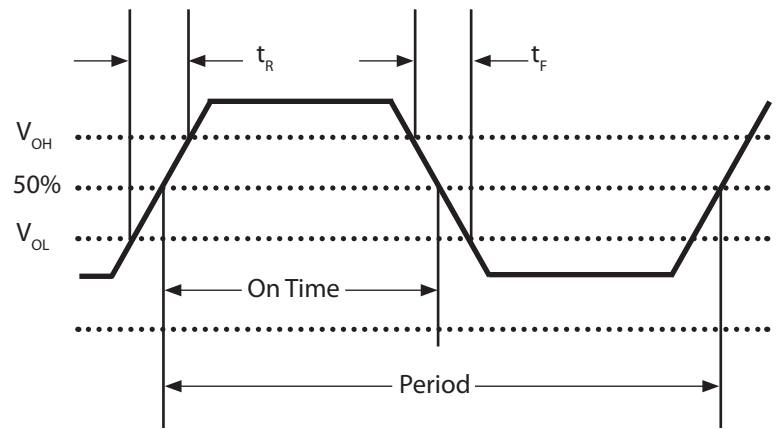
# Specifications

| Table 1. Electrical Performance                             |                      |                                   |         |                     |       |
|---|----------------------|-----------------------------------|---------|---------------------|-------|
| Parameter   | Symbol               | Min                               | Typical | Maximum             | Units |
| Frequency   | $f_o$                | 1.000                             |         | 150.000             | MHz   |
| Stability (ordering option) <sup>1</sup>                    | $\Delta f/f_o$       | ±25, ±50, ±100                    |         |                     | ppm   |
| Operating Temperature (ordering option)                     | $T_{OP}$             | -20/70 or -40/85                  |         |                     | °C    |
| Operating Supply Voltage <sup>2</sup><br>(ordering option)  | $V_{DD}$             | 1.65                              | 1.8     | 1.95                | V     |
|   |                      | 2.3                               | 2.5     | 2.7                 | V     |
|   |                      | 3.0                               | 3.3     | 3.6                 | V     |
| Supply Current, Output Enabled                              | $I_{DD}$             | 1 to 40MHz                        | 3       | 6                   | mA    |
|   |                      | 40.01 to 80MHz                    | 4       | 8                   | mA    |
|   |                      | 80.01 to 125MHz                   | 5       | 10                  | mA    |
|   |                      | 125.01 to 150MHz                  | 6       | 12                  | mA    |
| Supply Current, Output Disabled                             | $I_{DD}$             |                                   |         | 1                   | uA    |
| Output Logic Levels   | $V_{OH}$<br>$V_{OL}$ | $0.8 \cdot V_{DD}$                |         | $0.2 \cdot V_{DD}$  | V     |
|   |                      |                                   |         |                     | V     |
| Output Load   |                      | $\geq 10Kohm \parallel \leq 15pf$ |         |                     |       |
| Output Rise/Fall Time <sup>3</sup>                          | $t_R$<br>$t_F$       |                                   | 1.3     | 3                   | ns    |
|   |                      |                                   | 1.3     | 3                   | ns    |
| Duty Cycle <sup>4</sup>                                     | SYM                  |                                   |         | 45/55               | %     |
| Period Jitter <sup>5</sup> , RMS, 80MHz Output<br>Peak-Peak |                      |                                   | 9       |                     | ps    |
|   |                      |                                   | 75      |                     | ps    |
| Start-up Time   | $T_{SU}$             |                                   | 3       | 10                  | ms    |
| Enable/Disable <sup>6</sup>                                 | $V_{IH}$<br>$V_{IL}$ | $0.75 \cdot V_{DD}$               |         | $0.25 \cdot V_{DD}$ | V     |
|   |                      |                                   |         |                     | V     |

- 1] Stability includes initial accuracy, temperature and aging.
- 2] A 0.01uF and a 0.1uF capacitor should be located as close to the supply as possible (to ground) is recommended.
- 3] Figure 2 defines these parameters. Figure 1 illustrates the operating conditions under which these parameters are tested and specified.
- 4] Duty Cycle is measured defined as On Time/Period.
- 5] Measured using a Wavecrest SIA3300C, 90K samples
- 6] Output will be active if Enable/Disable is left open.



**Fig 1: Test Circuit**



**Fig 2: Output Waveform**

**Table 2. Absolute Maximum Ratings**

| Parameter                        | Symbol           | Ratings                    | Unit     |
|----------------------------------|------------------|----------------------------|----------|
| Power Supply                     | $V_{DD}$         | -0.3 to +4.0               | V        |
| CMOS Input Voltage               | E/D              | -0.3 to ( $V_{DD} + 0.3$ ) | V        |
| Junction Temperature             | $T_J$            | 150                        | °C       |
| Storage Temperature              | $T_{STR}$        | -55 to 125                 | °C       |
| Soldering Temperature / Duration | $T_{PEAK} / t_p$ | 260 / 40                   | °C / sec |

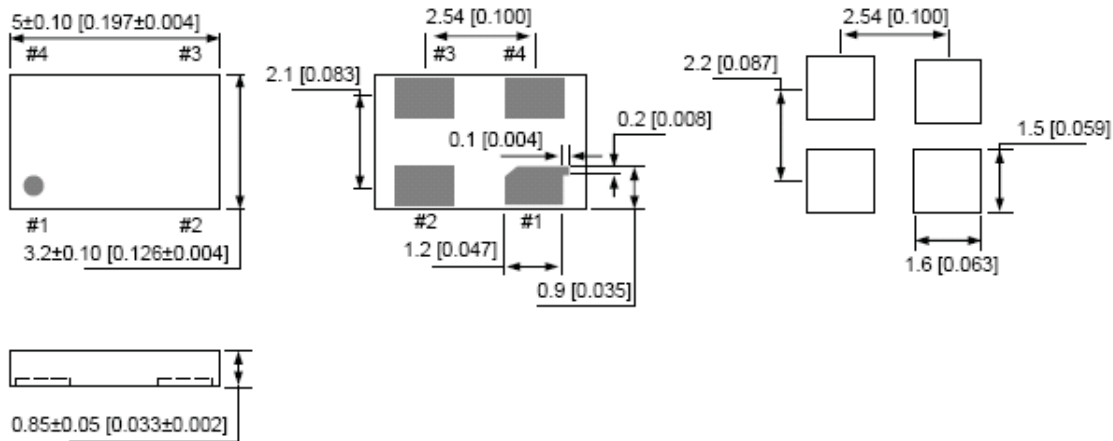
## Enable/Disable Functional Description

Under normal operation the E/D is set to a logic high state or logic low state. When E/D is set to a logic low, the oscillator stops and the output is in a high impedance state. This helps reduce power consumption as well as facilitating board testing and troubleshooting. When E/D is set to a logic high state, the oscillator produces an output. Leaving the Enable/Disable pin open results in an active state with an output frequency.

## Outline Drawing

## Suggested Pad Layout

Units: mm (inches)



Contact Pads are  
Gold flash (0.003 um min ) over  
Palladium (0.01-0.15um)  
Nickel (0.508-2.032um)

**Figure 3**

**Table 3. Pin Out**

| Pin | Symbol   | Function          |
|-----|----------|-------------------|
| 1   | E/D      | Enable/Disable    |
| 2   | GND      | Electrical Ground |
| 3   | $f_o$    | Output Frequency  |
| 4   | $V_{DD}$ | Supply Voltage    |

# Reliability

**Table 4. Environmental Compliance**

| Parameter                  | Conditions               |
|----------------------------|--------------------------|
| Mechanical Shock           | MIL-STD-202, Method 2002 |
| Mechanical Vibration       | MIL-STD-883, Method 2007 |
| Temperature Cycle          | MIL-STD-883, Method 1010 |
| Gross and Fine Leak        | MIL-STD-883, Method 1014 |
| Resistance to Solvents     | MIL-STD-202, Method 215  |
| Moisture Sensitivity Level | MSL1                     |

## Handling Precautions

Although ESD protection circuitry has been designed into the VM-800, proper precautions should be taken when handling and mounting. VI employs a Human Body Model and a Charged-Device Model (CDM) for ESD susceptibility testing and design protection evaluation. ESD thresholds are dependent on the circuit parameters used to define the model.

**Table 5. ESD Ratings**

| Model                | Minimum |
|----------------------|---------|
| Human Body Model     | 2000V   |
| Charged Device Model | 500V    |
| Machine Model        | 200 V   |

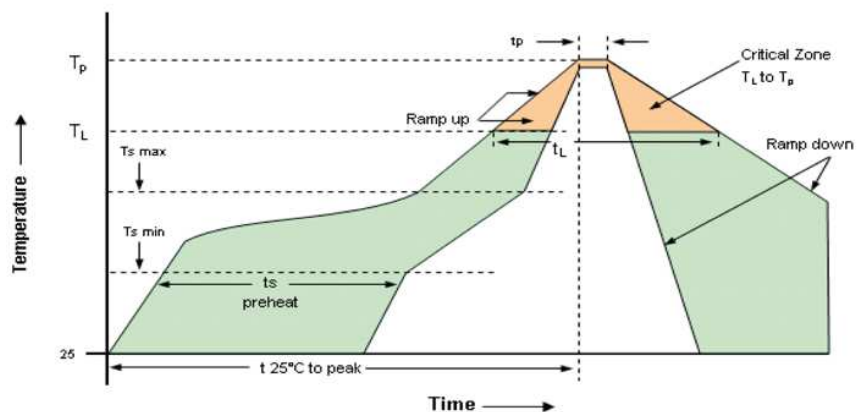
## Suggested IR Profile

Devices are built using lead free epoxy and can also be subjected to standard lead free IR reflow conditions. Figure 6 shows max temperatures and lower temperatures can also be used e.g. peak temperature of 220C.

**Table 6. Reflow Profile**

| Parameter                        | Symbol              | Value                                     |
|----------------------------------|---------------------|---|
| PreHeat Time<br>Ts-min<br>Ts-max | $t_s$               | 60 sec Min, 260 sec Max<br>150°C<br>200°C |
| Ramp Up                          | $R_{UP}$            | 3 °C/sec Max                              |
| Time Above 217 °C                | $t_L$               | 60 sec Min, 150 sec Max                   |
| Peak Temperature                 | $t_p$               | 255-260°C                                 |
| Time To Peak Temperature         | $T_{25C\ to\ Peak}$ | 480 sec Max                               |
| Time at Peak Temperature         | $t_p$               | 20 sec Max                                |
| Ramp Down                        | $R_{DN}$            | 6 °C/sec Max                              |

**Solderprofile:**



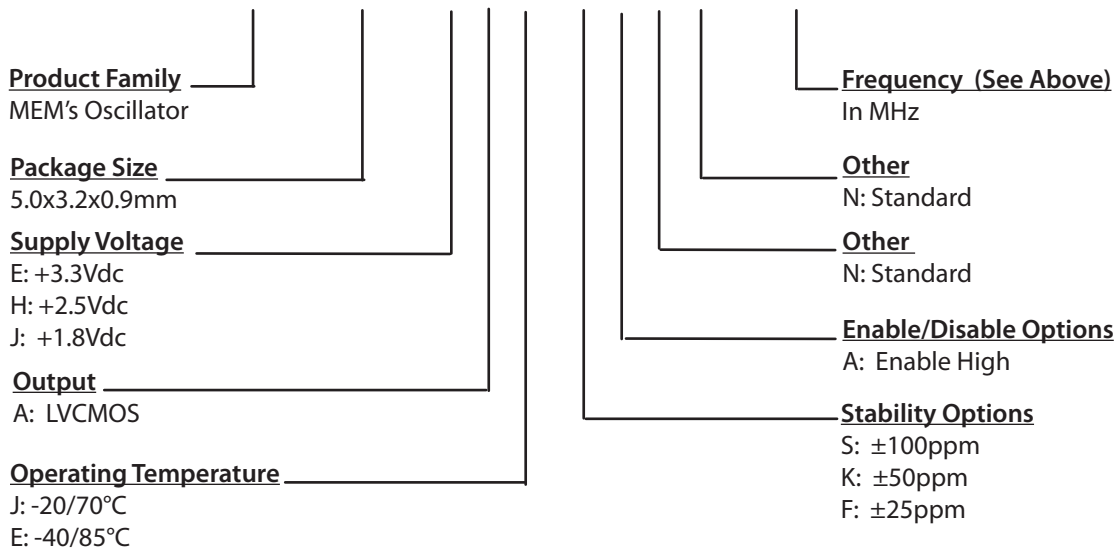
**Figure 4**

## Ordering Information

| Standard Frequencies (MHz) |         |         |        |        |         |          |         |         |         |
|----------------------------|---------|---------|--------|--------|---------|----------|---------|---------|---------|
| 2.000                      | 3.686   | 4.000   | 4.032  | 4.9152 | 5.000   | 6.000    | 7.3728  | 7.680   | 8.000   |
| 9.216                      | 9.600   | 10.000  | 12.000 | 12.500 | 12.729  | 14.31818 | 14.746  | 16.000  | 16.128  |
| 17.000                     | 20.000  | 21.000  | 21.500 | 22.000 | 23.000  | 24.000   | 25.000  | 26.000  | 27.000  |
| 29.4912                    | 30.000  | 32.000  | 33.000 | 33.333 | 36.000  | 37.500   | 40.000  | 42.500  | 45.000  |
| 48.000                     | 50.000  | 55.000  | 56.448 | 58.320 | 60.000  | 64.000   | 66.000  | 66.666  | 72.000  |
| 75.000                     | 80.000  | 83.333  | 84.000 | 95.000 | 100.000 | 110.000  | 112.500 | 114.000 | 115.200 |
| 116.640                    | 125.000 | 127.872 |        |        |         |          |         |         |         |

Other Frequencies Available Upon Request.

## VM-800-EAE-KANN- xxMxxxxxxxxx



Example: VM-800-EAE-KANN-125M000000 = 5x3.2, +3.3V, LVCMOS output, ±50ppm over -40/85°C with a 125.000MHz output

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